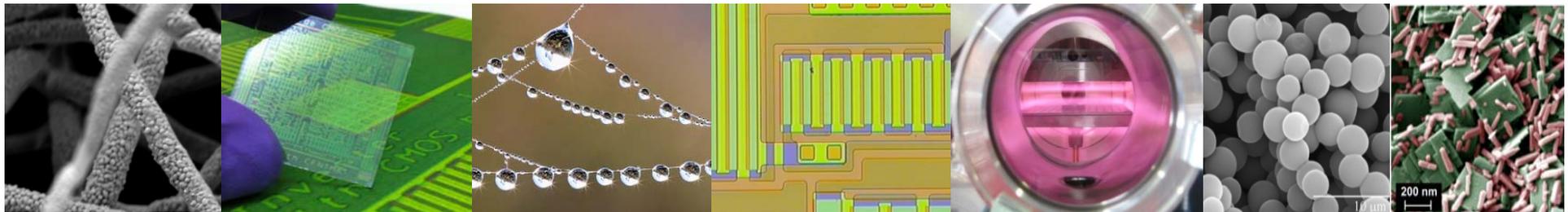


i3N

Institute of Nanostructures, Nanomodelling and Nanofabrication

**Materials for Electronics, Optoelectronics and
Nanotechnologies (MEON) – *Prof. Rodrigo Martins***



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Aveiro, 10 April, 2015



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General Outline

- **Transparent Electronics**
- **Paper Electronics**
- **Electrochemical Devices**
- **Biosensors/Microfluidics**
- **Nanoplasmonics**

Transparent Electronics

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Transparent Electronics

What?

New materials and processes for conventional thin film technology

- Replace conventional oxide thin films by random networks of NWs
- Future TCOs

Ordered arrays of oxide semiconductor NWs for ultimate oxide nanoscale performance

Speed, scientific/technological challenge

- Indium-free semic.
- Hybrid dielectrics...
- Solution processing

How?

- Transfer and direct grow methods
- Aligned and ordered arrays using NIL seed layers

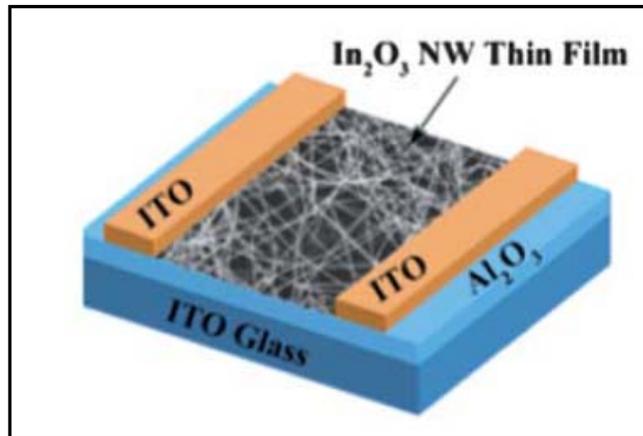
- Spin-coating or printing of NW solution in μm -scale devices.
- Grids/meshes of metallic NWs

Process and device simulation + novel circuit design for high performance/low power consumption

Transparent Electronics

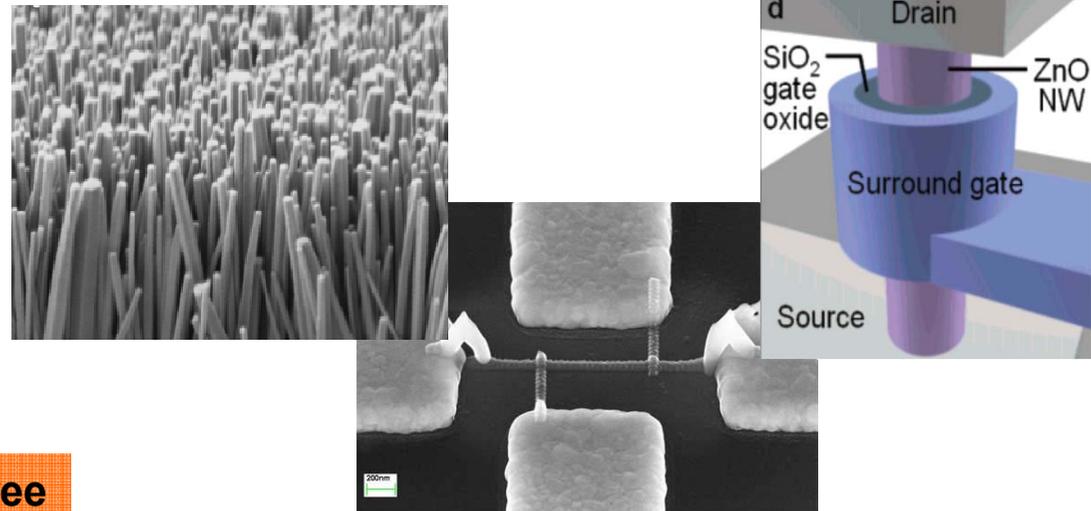
Materials and device structures

Random networks of oxide NWs



- Hydrothermal synthesis of **indium-free** oxide semiconductor NWs (e.g. ZTO)
- Synthesis decoupled from deposition – easy migration to **flexible substrates**
- $\mu > 100 \text{ cm}^2/\text{Vs}$, $L \approx 1 \text{ }\mu\text{m}$, kHz-low MHz operation

Ordered arrays of oxide NWs



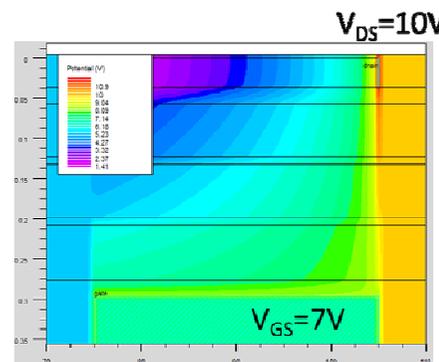
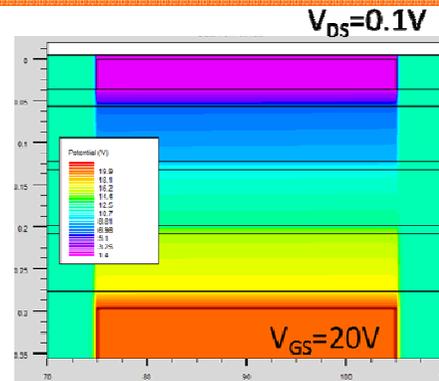
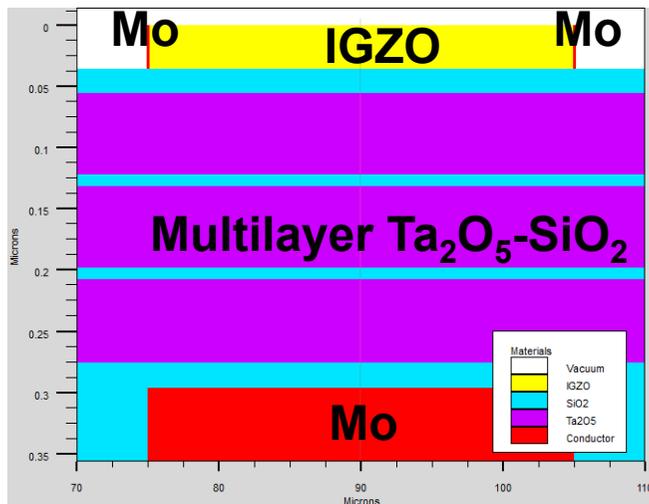
- Full device @ nanoscale: **speed+multifunctionality**
- Precise positioning with NIL and EBL
- High density of surrounding gate structures
- $\mu > 1000 \text{ cm}^2/\text{Vs}$, $L < 50 \text{ nm}$, GHz operation

+ Integration with transparent metal nanostructures (nanoscale TCOs, $\downarrow R_s$,

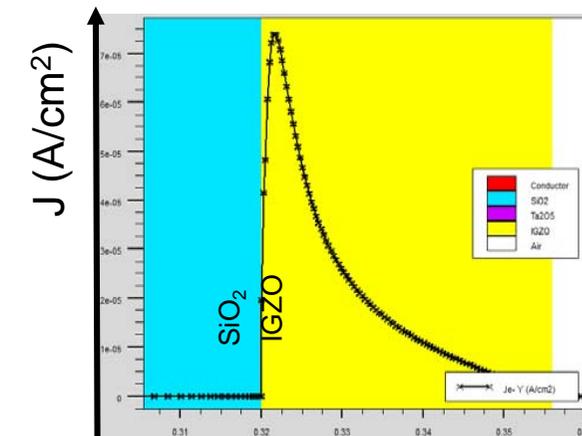
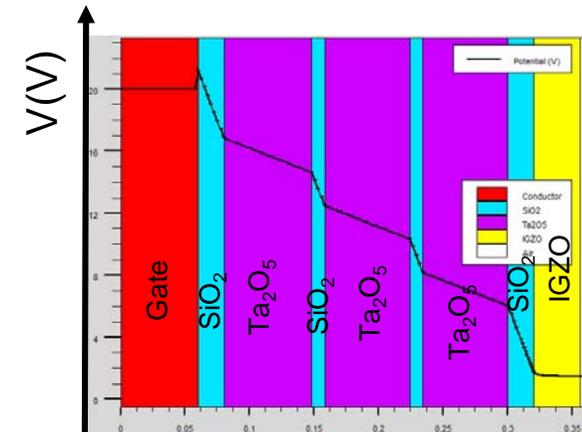
Transparent Electronics

Process and device simulation

- Optimize vacuum/non-vacuum deposition routes
- Insights on device physics, stability improvement
- Prediction of device/circuit performance depending on processing conditions and device structure
- Work already started with **SILVACO TCAD** on sputtered IGZO TFTs, will expand to other materials/structures

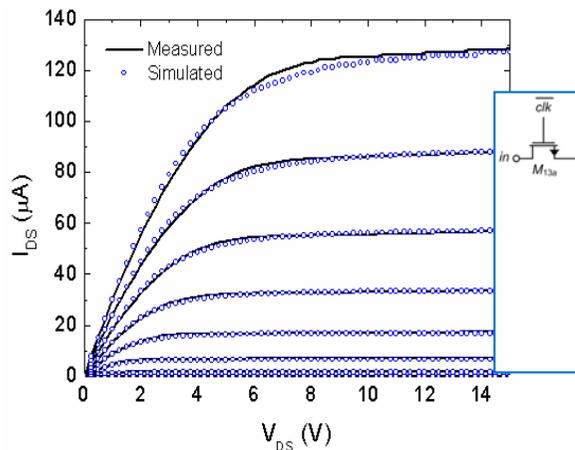


Potential and current density distribution



Building of PDK to create more complex circuits, μm and nm scale devices

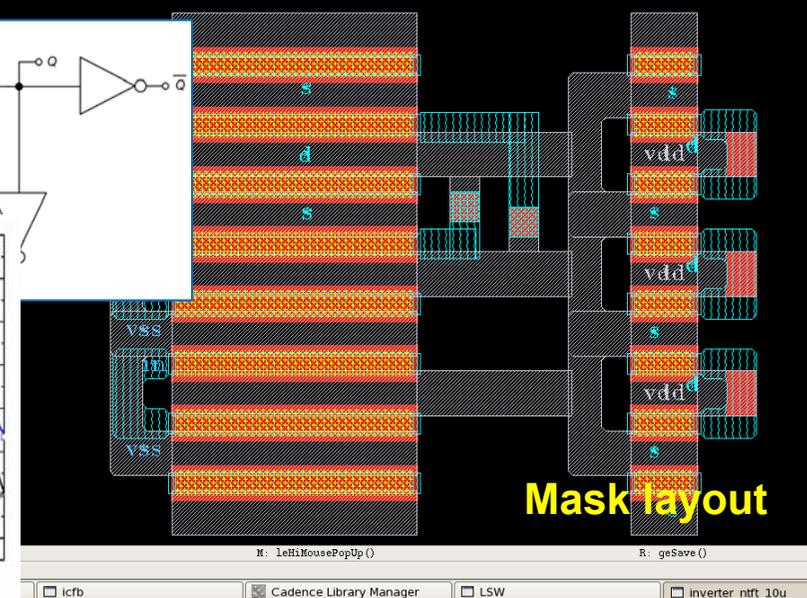
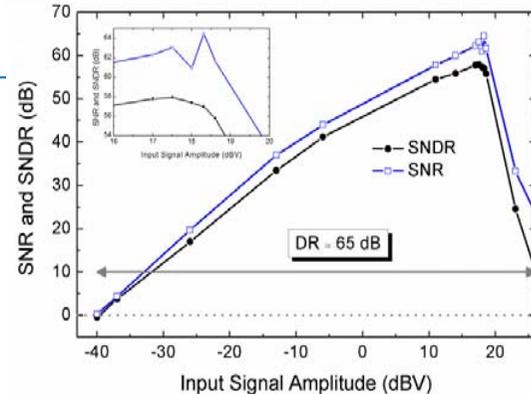
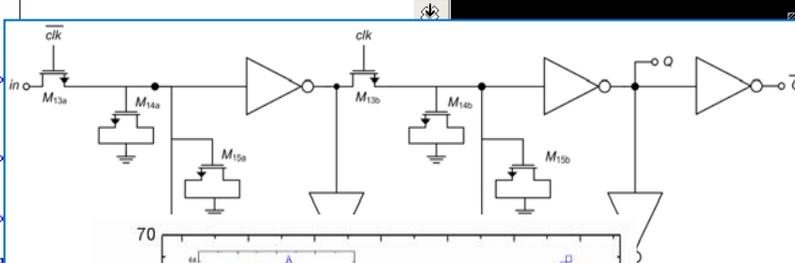
- Standard cell library
- Design rule check, layout-versus-schematic, parasitics (DRC, LVS, RCX)
- Simulation models
- nMOS and CMOS architectures



TFT models

Circuit schematic and simulation

Example of a differential 2nd order CT $\Sigma\Delta\text{M}$ with feedforward structure



P.G. Bahubalindrani, V.G. Tavares, P. Barquinha, C. Duarte, N. Cardoso, P.G. de Oliveira, R. Martins, E. Fortunato, "a-GIZO TFT neural modeling, circuit simulation and validation", **Solid State Electronics**, 105 (2015), pp. 30-36.

Paper Electronics

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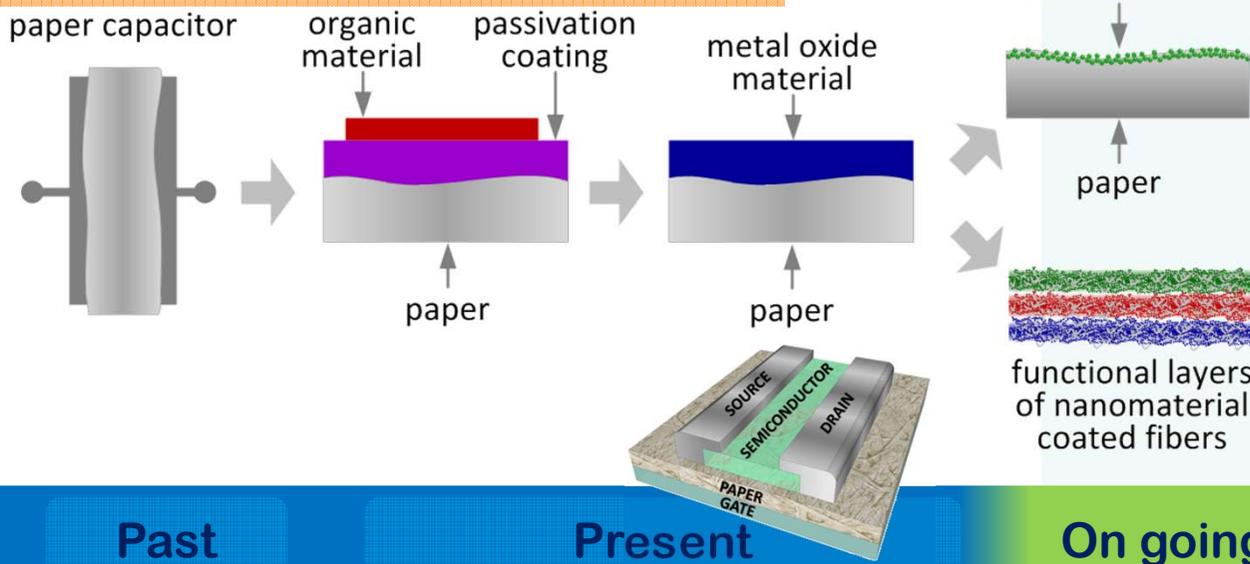
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Paper Electronics

Bottlenecks/opportunities

- Paper substrates
- Deposition of functional materials
- Proper functionality



“There is increasing work on printed inorganics as people struggle with the performance of organics... for transistor semiconductors with ten times the mobility, look to the new inorganics.”

ID TechX , 2014-2024: Needs, Opportunities, Forecasts.

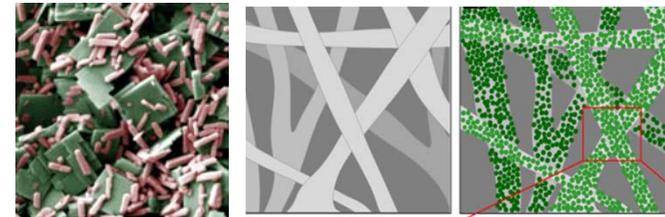
- Cellulose nanocomposites
- Low cost devices/systems
- Sustainability/Recyclability
- New Markets/Benefits PT/EU INDs.

R. Martins, et al., Recyclable, Flexible, Low-Power Oxide Electronics, *Advanced Functional Materials* 23 (17) (2013), pp. 2153-2161

Paper Electronics

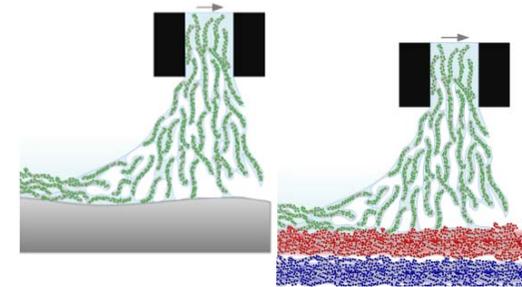
Multifunctional materials

- Inorganic/hybrid particles
- Functional cellulose



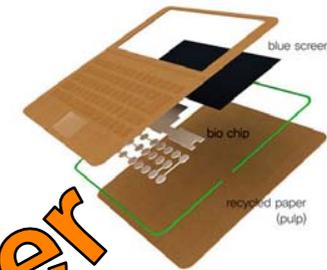
Deposition and formation

- Inks/dispersions
- Paper/films formation



Devices

- Cellulose based electrical and electrochemical components



Systems

- Integration
- Proof of concept

(Re)Inventing the paper

L Pereira, D Gaspar, D Guerin, A Delattre, E Fortunato and R Martins, The influence of fibril composition and dimension on the performance of paper gated oxide transistors, **Nanotechnology** 25 (2014) art n° 094007 (11pp).

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Paper Electronics



Electrochemical Devices

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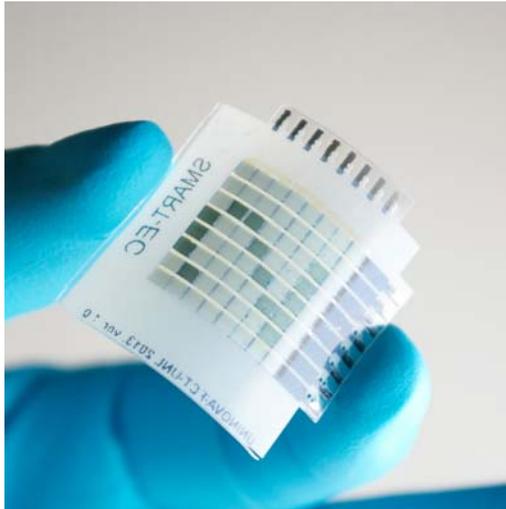
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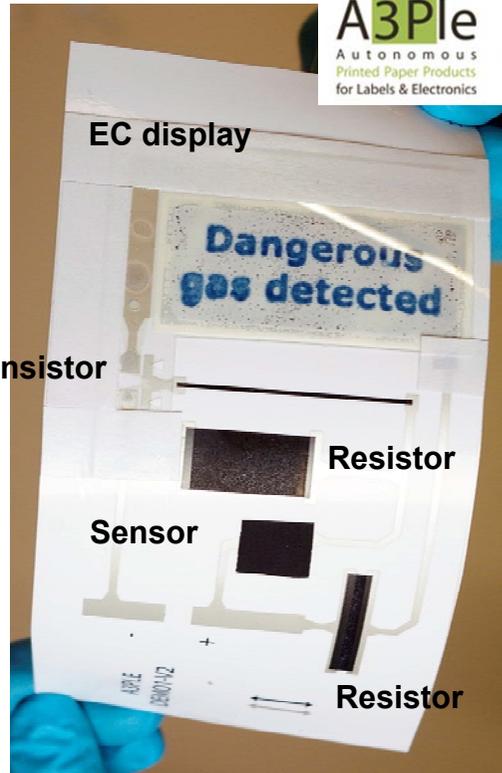
Electrochemical Devices



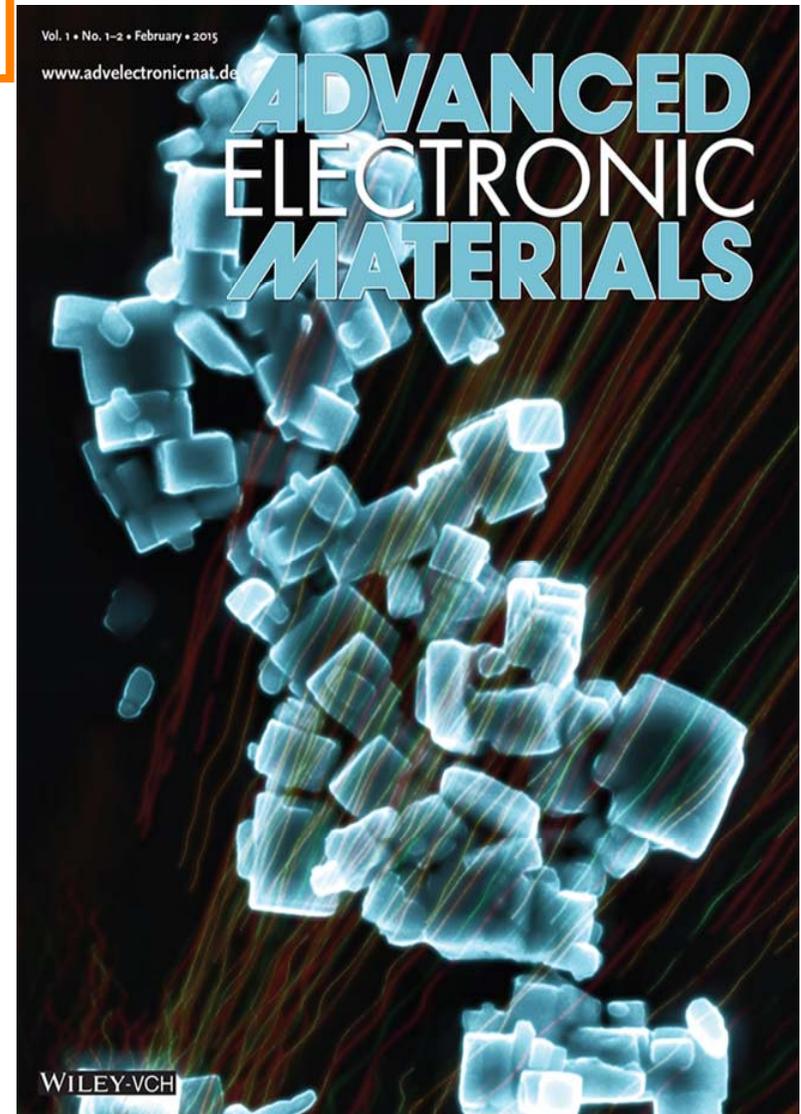
www.smart-ec.eu



Printed, flexible, all-solid-state, 8x8 passive **electrochromic** matrix (display), 1.65x1.65 mm pixel.



Inkjet/screen printed, **all-solid-state, bendable, paper display**
Printed circuits and **transistors.**



L. Santos, P. Wojcik, J.V. Pinto, E. Elangovan, J. Viegas, L. Pereira, R. Martins, E. Fortunato "Structure and Morphologic Influence of WO₃ Nanoparticles on the Electrochromic Performance of Dual-Phase α -WO₃/WO₃ Inkjet Printed Films", **Advanced Electronic Materials**, 2015,

13 DOI: 10.1002/aelm.201400002.

Aveiro, 10 April, 2015



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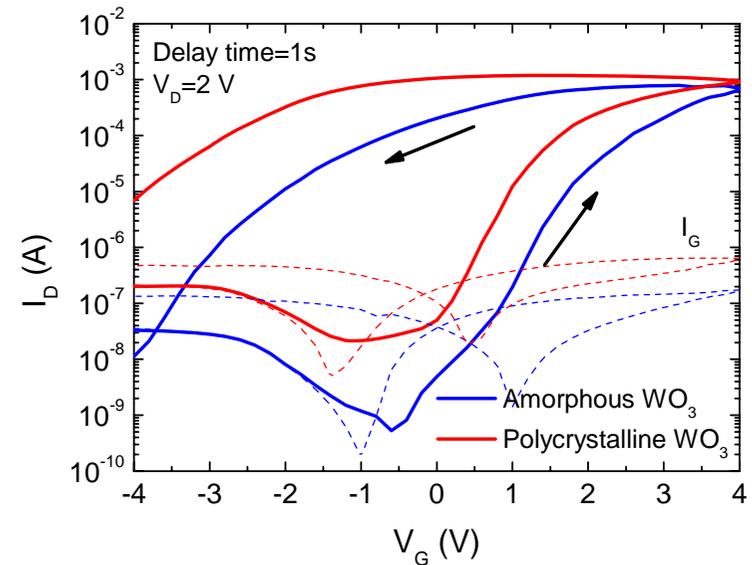
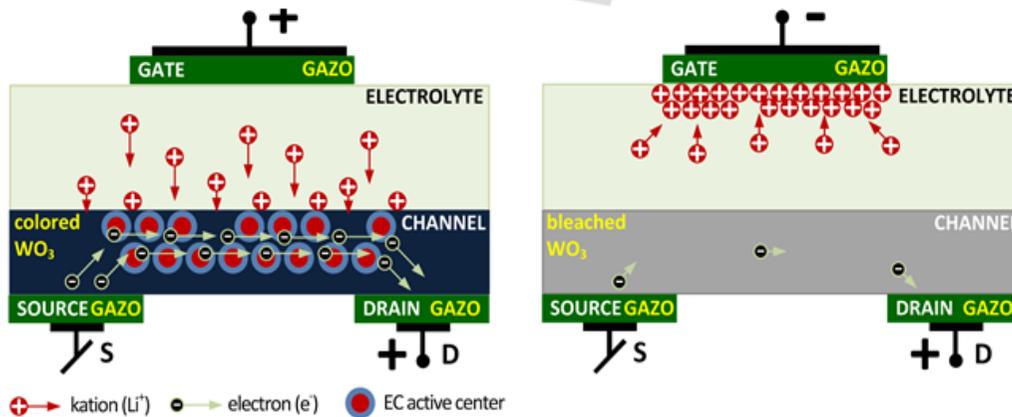
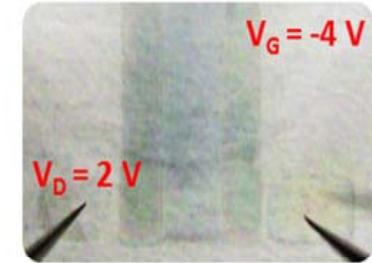
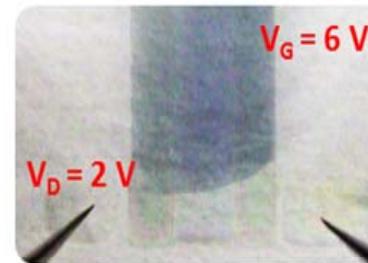
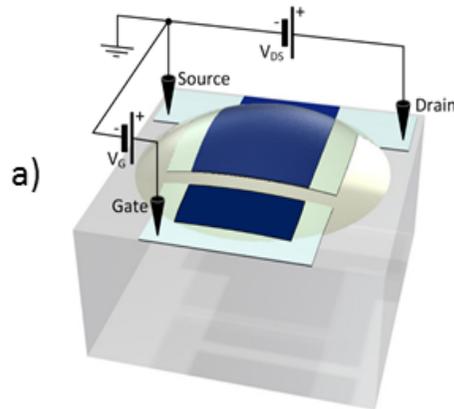


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Electrochemical Devices

EGT WO_3 transistors with electrical and optical modulation



P. Barquinha, et al., accepted **Advanced Electronic Materials**, 2015.

Biosensors/Microfluidics

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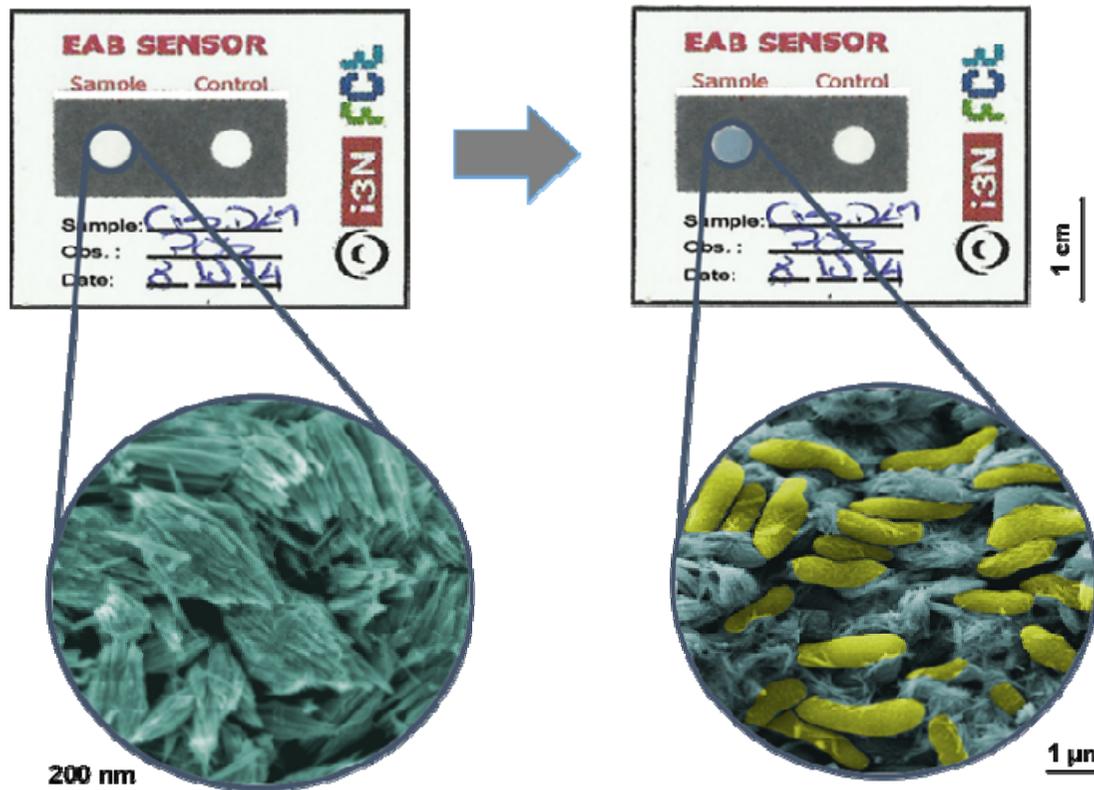


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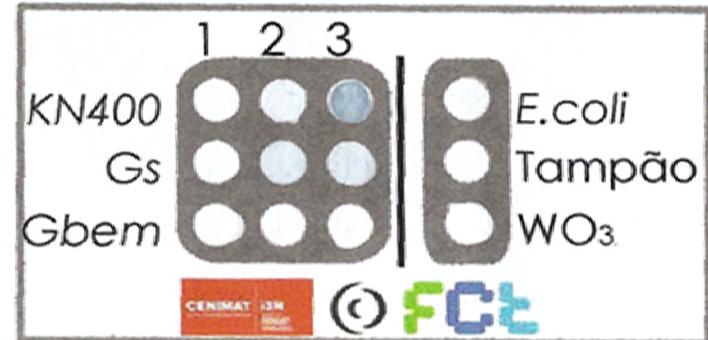
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Biosensors/Microfluidics

WO₃ NPs used as Bioelectrochromic Detection of Electrochemically Active Bacteria



Sensor with different bacteria

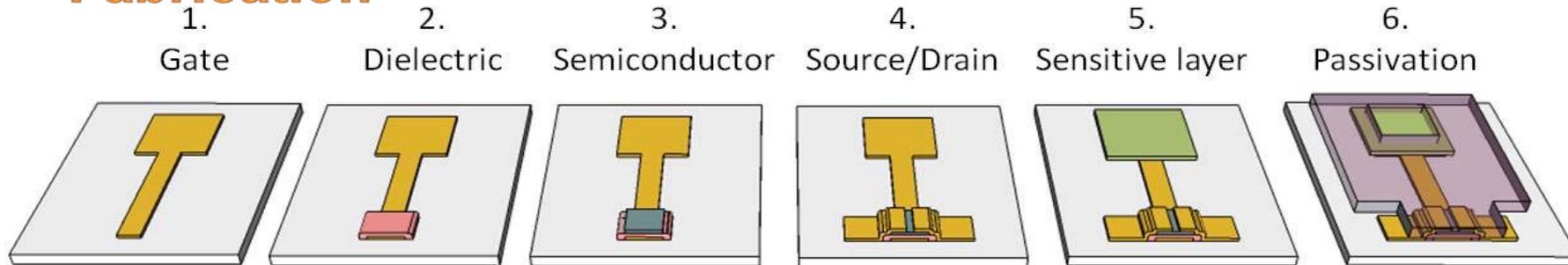


KN400 – *Geobacter sulfurreducens*, strain KN400
 Gs – *Geobacter sulfurreducens*, strain DL1
 Gbem – *Geobacter bemidjiensis*

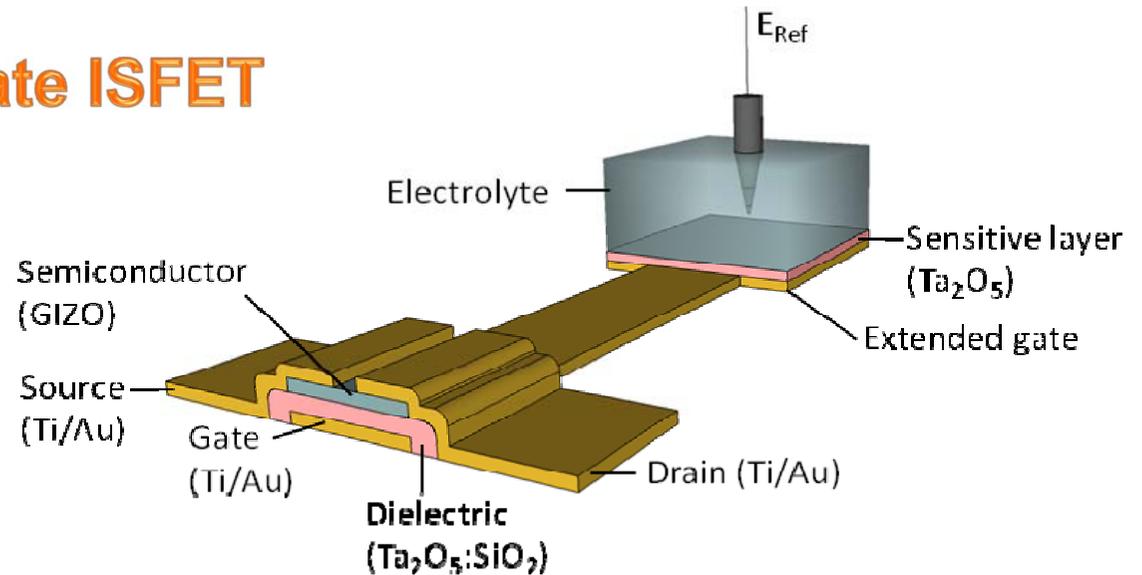
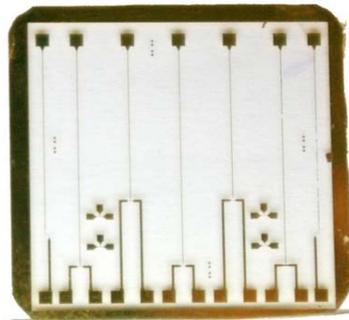
Color distinction between the electron transfer ability of the bacteria to the WO₃ probe, and consequently, to generate current!

A.C. Marques, et al., accepted **Scientific Reports**, 2015.

Fabrication



Structure: Extended Gate ISFET

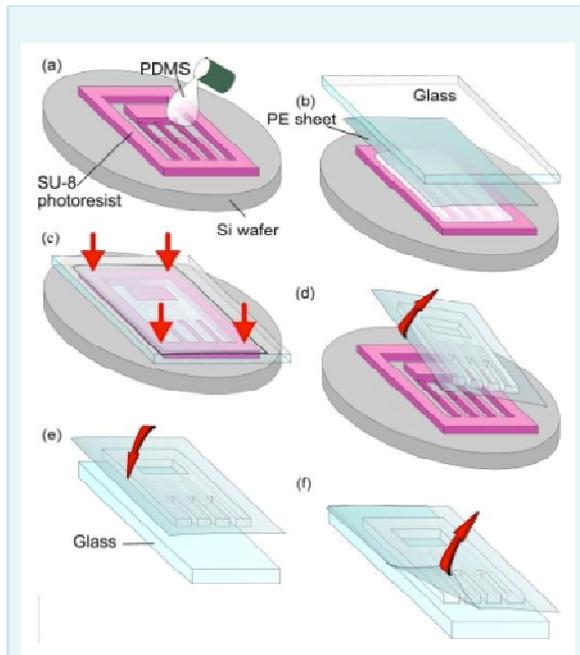


Bruno Veigas, Rita Branquinho, Joana Pinto, Pawel Wojcik, Rodrigo Martins, Elvira Fortunato, Pedro V Baptista, Ion sensing (EIS) real-time quantitative monitorization of isothermal DNA amplification, **Biosensors & Bioelectronics** Vol 52 (2014), pp. 50-5.

Biosensors/Microfluidics

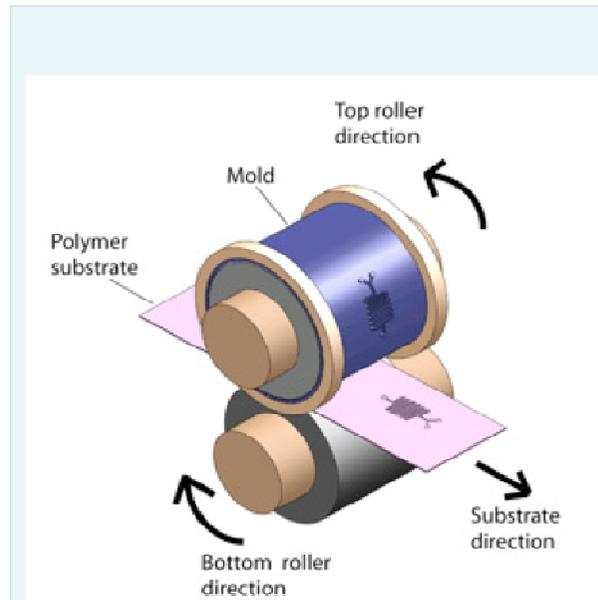
Microfluidic technologies

SU8/PDMS Lithography



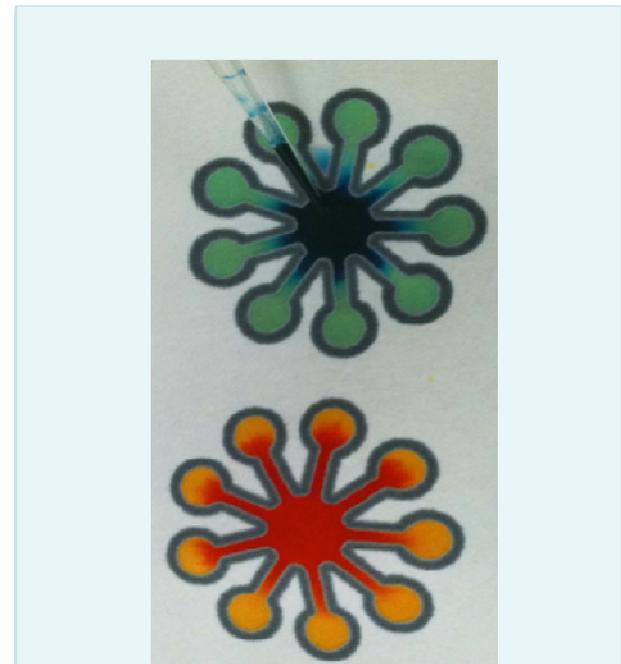
Schematic illustration of the simplified fabrication process for PDMS microfluidic alginate microbead generator chip.

Embossing



Embossing depicting the principle of fabrication of polymer-based microfluidic devices using the hot roller embossing technique.

Lab-on-Paper



Example of paper microfluidic devices developed at FCT-UNL, Portugal.

Complexity
Cost

Safety
Time

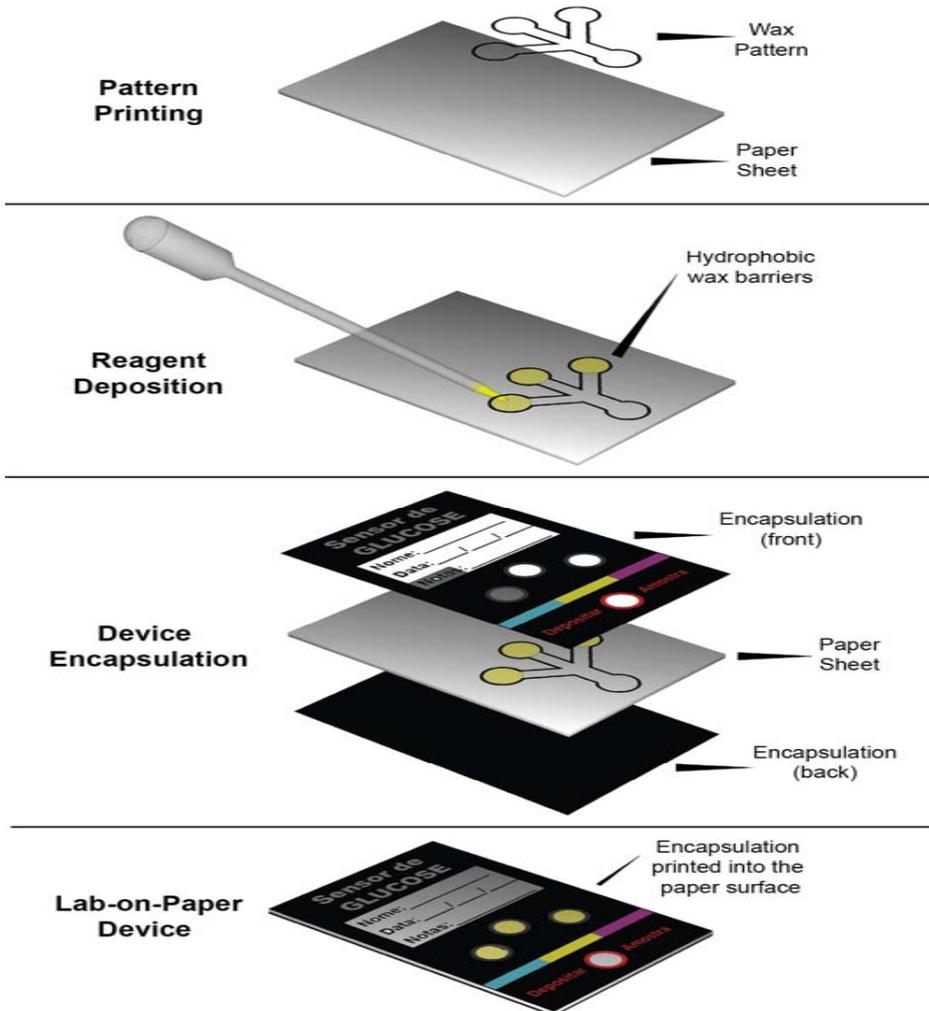
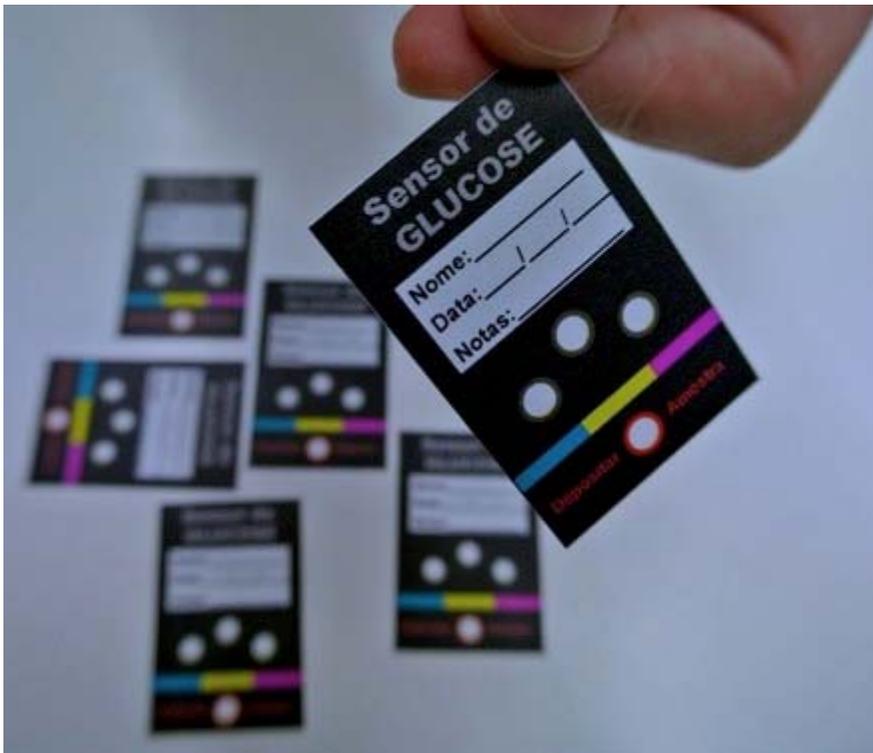
energy
Resolution



Biosensors/Microfluidics Lab-on-Paper

Glucose biosensor

Paper Analytical Device



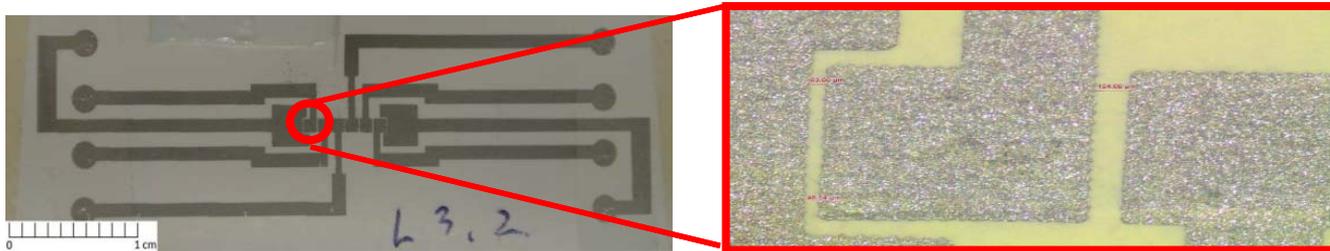
M N Costa, B Veigas, J M Jacob, D S Santos, J Gomes, P V Baptista, R Martins, J Inácio and E Fortunato, A low cost, safe, disposable, rapid and self-sustainable paper-based platform for diagnostic testing: lab-on-paper, **Nanotechnology** 25 (2014) art

1 n° 094006.

Biosensors/Microfluidics

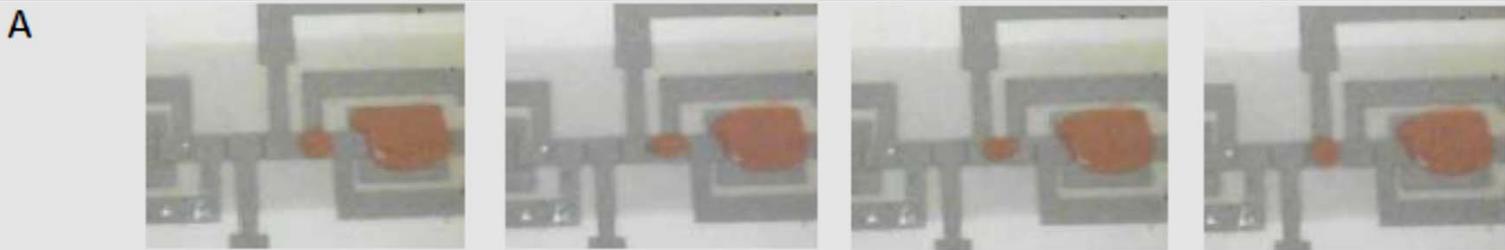
Digital Microfluidics

Paper-based devices



Screen printed electrodes

Droplet dispensing



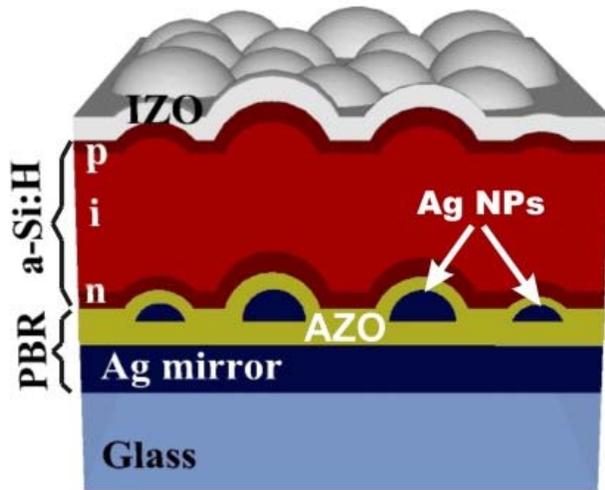
Droplet merging



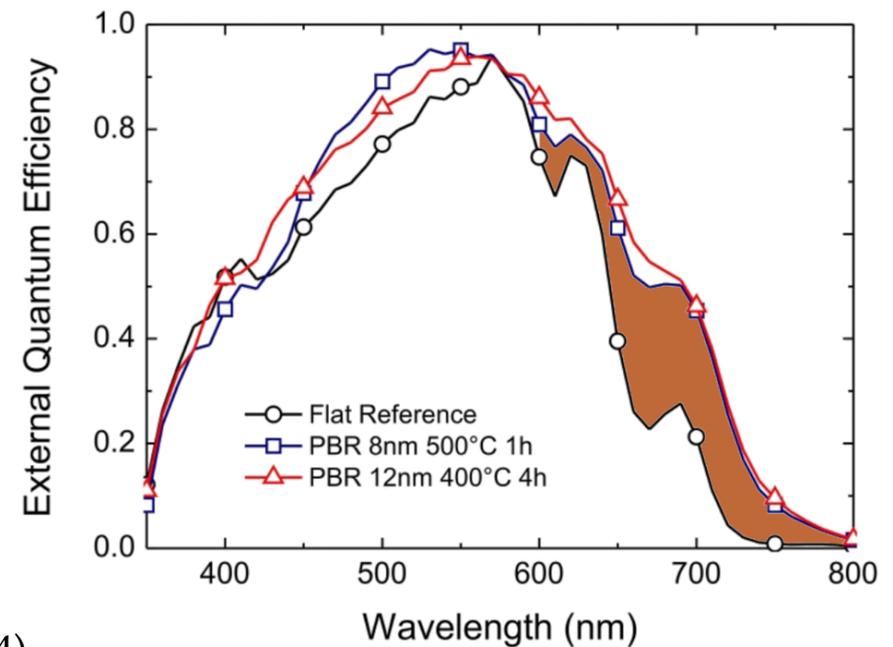
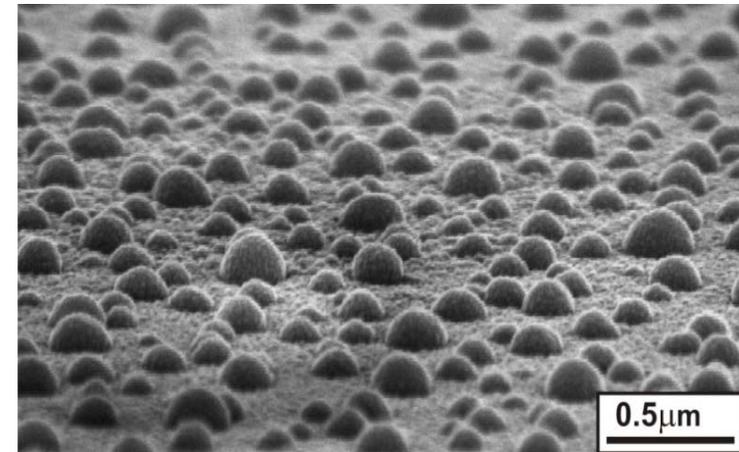
time →

Nanoplasmonics

Plasmonic Back Reflectors with Ag NPs formed by Thin Film Annealing (solid-state dewetting)



- 22.3% current (J_{sc}) enhancement
- **25.2% efficiency enhancement**

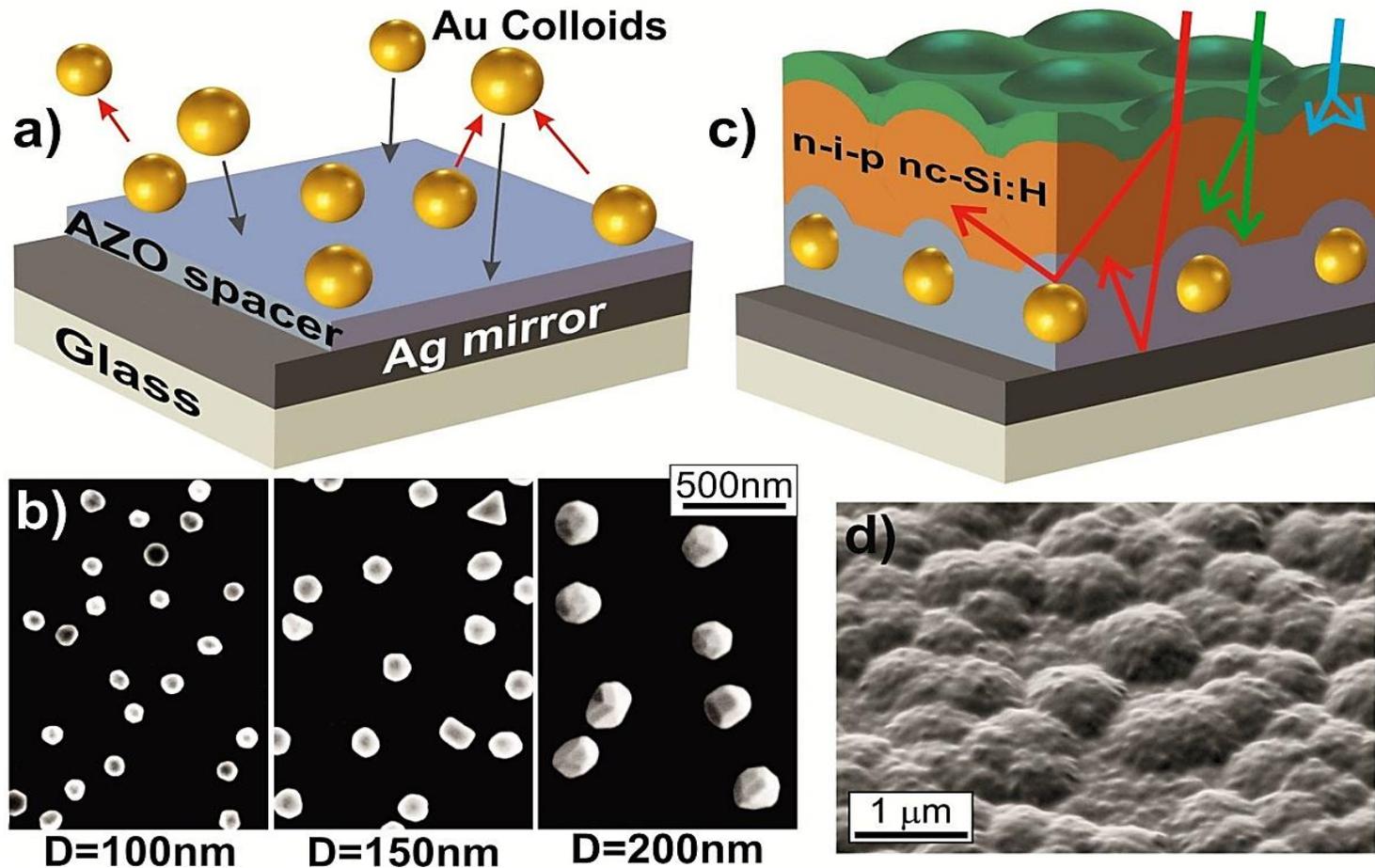


S. Morawiec, M. J. Mendes *et al.* Optics Express (2014)

Nanoplasmonics

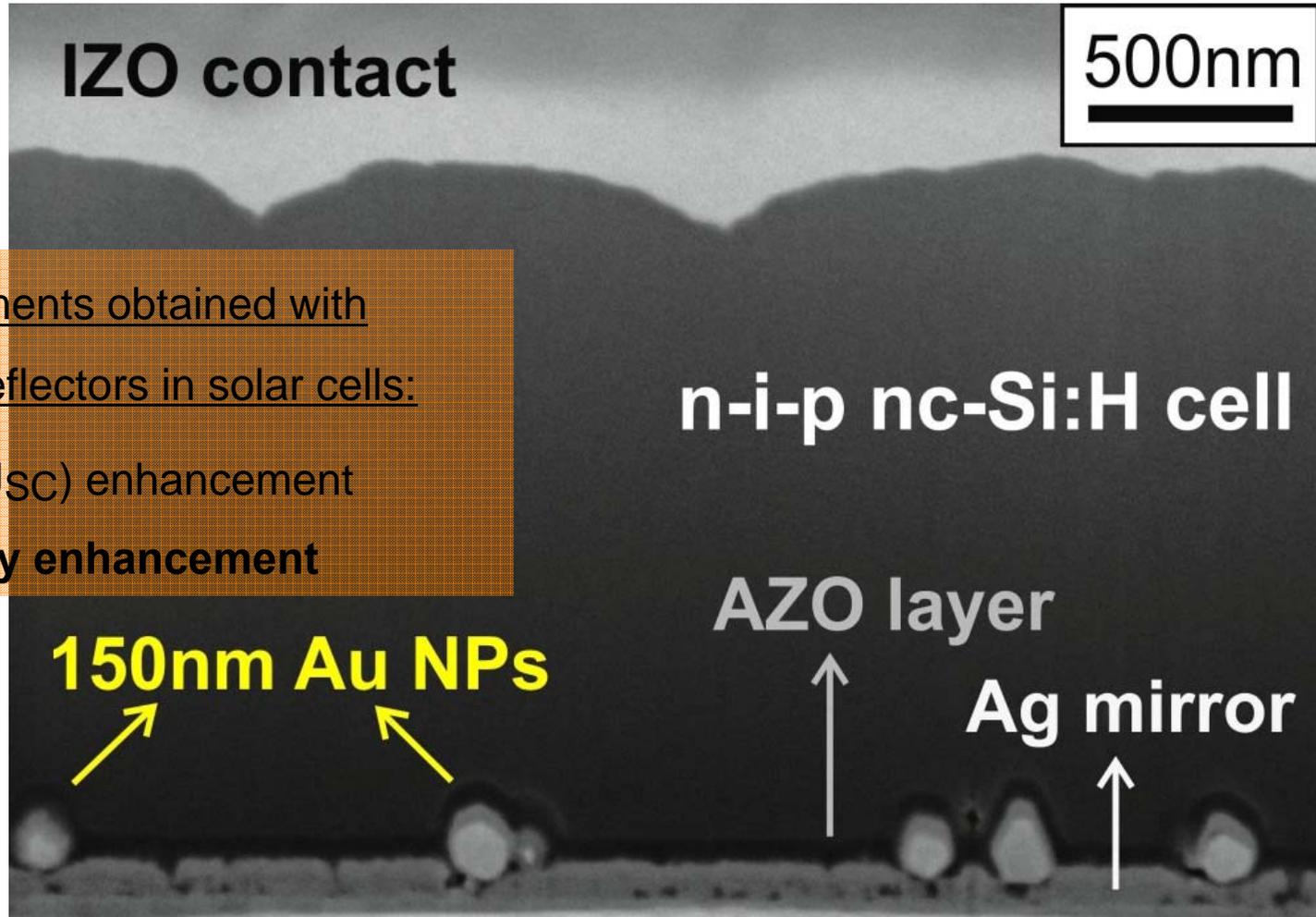
M. J. Mendes, S. Morawiec *et al.*
Nanoscale 6 (2014)

Novel Plasmonic Back Reflectors with Spherical Au NPs formed by Colloidal Self-Assembly (wet coating)



Nanoplasmonics

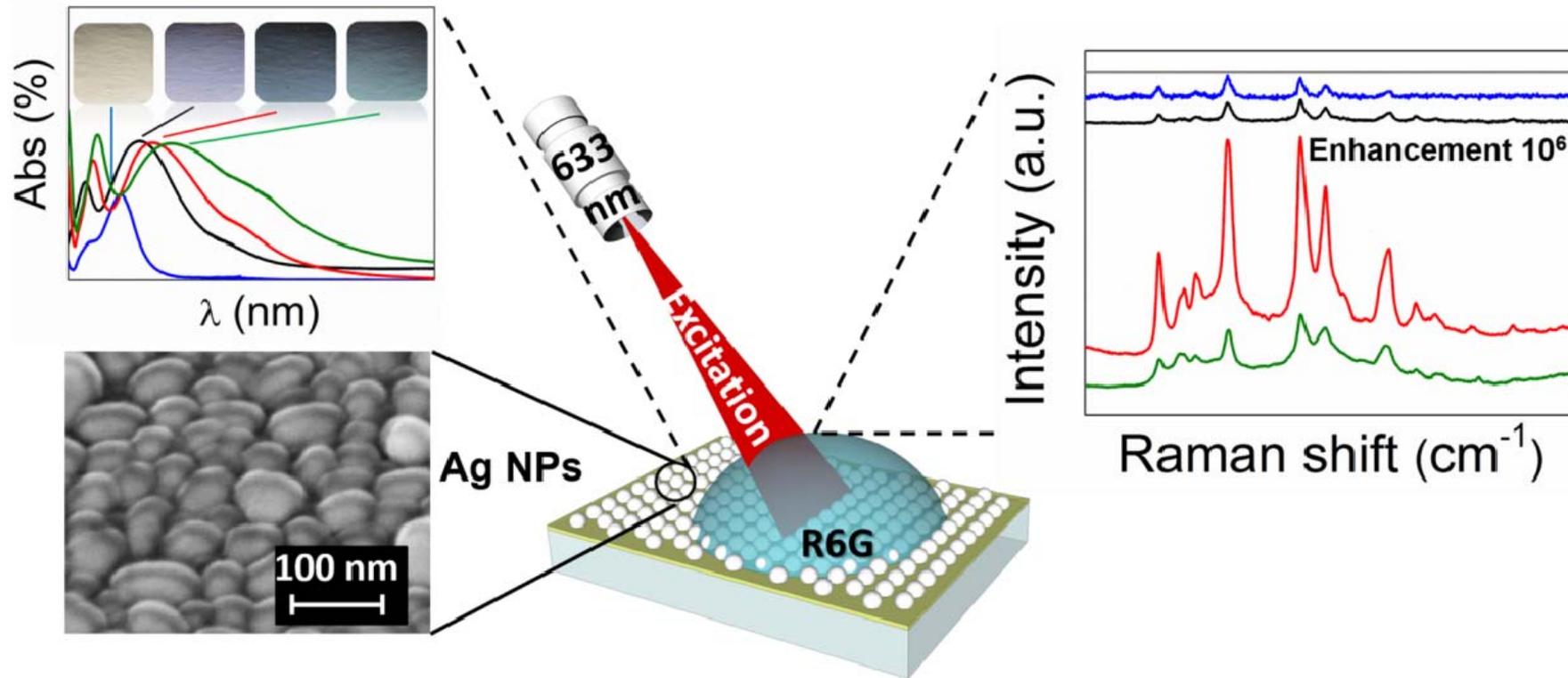
Novel PBRs formed by Colloidal Self-Assembly



Record enhancements obtained with plasmonic back reflectors in solar cells:

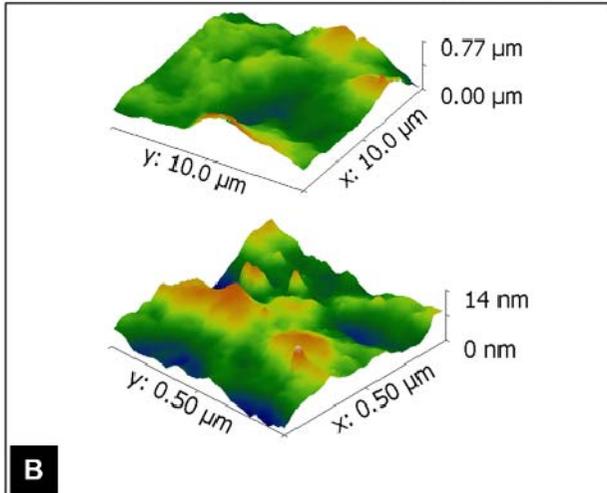
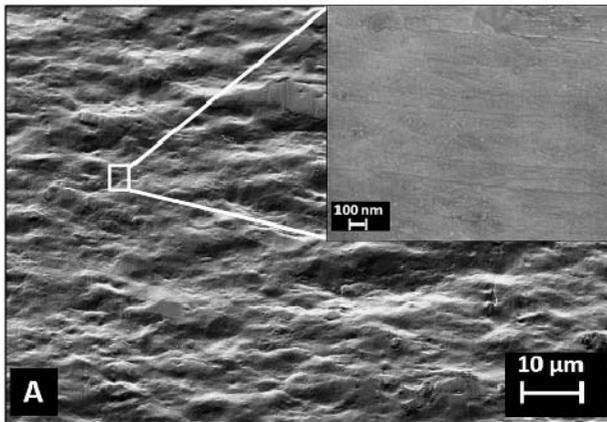
- 43% current (J_{SC}) enhancement
- **41% efficiency enhancement**

M. J. Mendes, S. Morawiec *et al.* *Nanotechnology* 26 (2015)

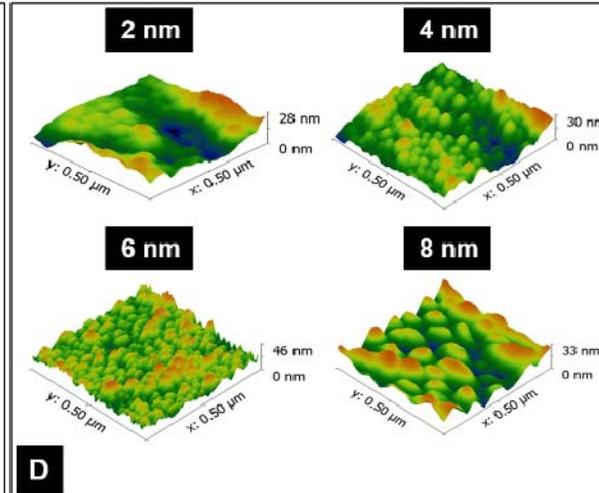
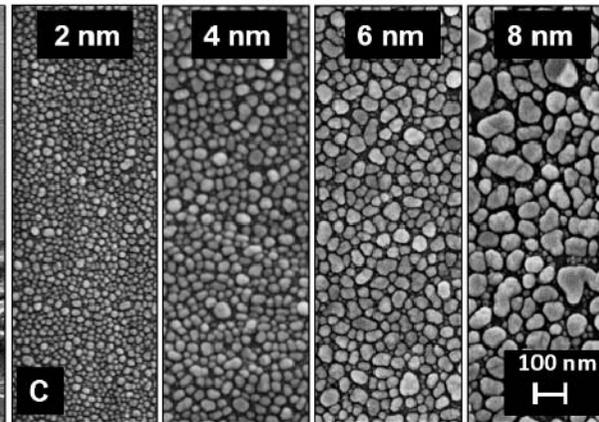


Araujo, A., C. Caro, M.J. Mendes, D. Nunes, E. Fortunato, R. Franco, H. Aguas, and R. Martins, *Highly efficient nanoplasmonic SERS on cardboard packaging substrates*. *Nanotechnology*, 2014. **25**(41): p. 415202

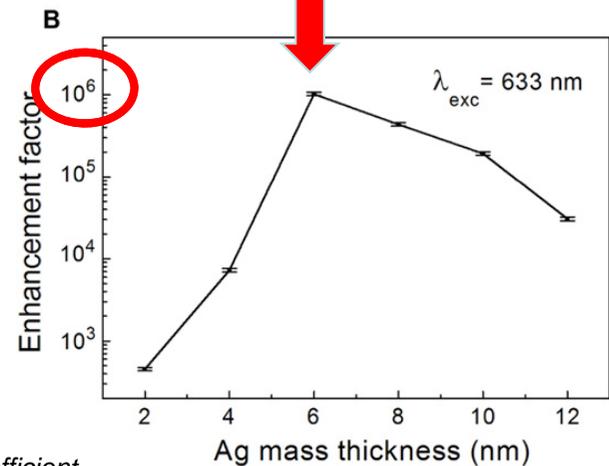
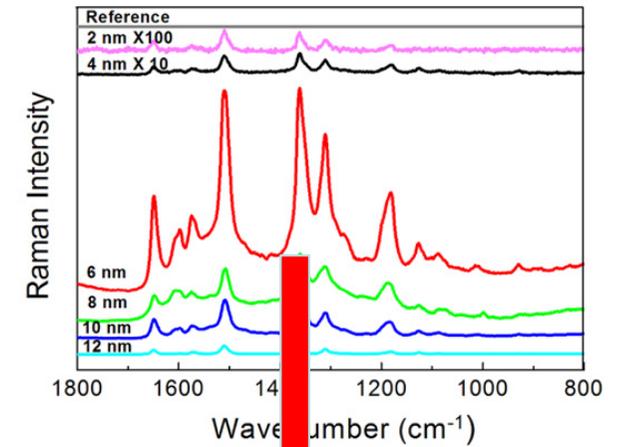
Cardboard Surface



Ag Nanoparticles



A SERS with R6G



Araujo, A., C. Caro, M.J. Mendes, D. Nunes, E. Fortunato, R. Franco, H. Aguas, and R. Martins, *Highly efficient nanoplasmonic SERS on cardboard packaging substrates*. *Nanotechnology*, 2014. **25**(41): p. 415202

Running FP7/H2020 projects

CoG ERC, CapTherPV, Grant n° 647596
StG ERC, NewFun, Grant n° 640598



iFLEXIS, Grant n° 611070 (ICT)
AlIOxidePV, Grant n° 309018 (FET)
APPLE, Grant n° 262782 (NMP)
CEOPS, Grant n° 309984 (NMP)
MATCH, Grant n° 319142 (CSA)
InnoNet, Grant n° 319024 (CSA)
Roll-Out, Grant n° 644631 (ICT)
TRANSFLEXTEG, Grant n° 645241 (ICT)
Symbiotic, Grant n° 665046 (FET)

